TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOSVI)

TPC8126

Lithium Ion Battery Applications Power Management Switch Applications

- Small footprint due to small and thin package
- Low drain-source ON-resistance: R_{DS} (ON) = 7.5 m Ω (typ.)
- Low leakage current: $I_{DSS} = -10 \ \mu A \ (max) \ (V_{DS} = -30 \ V)$
- Enhancement mode: V_{th} = -0.8 to -2.0 V (V_{DS} = -10 V, I_D = -0.5mA)

Absolute Maximum Ratings (Ta = 25°C)

				$\left(\begin{array}{c} \\ \\ \end{array} \right)$
Characteristics		Symbol	Rating	Unit
Drain-source voltage		V _{DSS}	-30	V
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)		V _{DGR}	-30	v
Gate-source voltage		V _{GSS}	-25/+20	v
Drain current	DC (Note 1)	I _D	-11	А
	Pulse (Note 1)	I _{DP}	44	^
Drain power dissipatio	n (t = 10 s) (Note 2a)	PD	1.9	W
Drain power dissipatio	n (t = 10 s) (Note 2b)	PD	1.0	w
Single pulse avalanche	e energy (Note 3)	EAS	79	Lm
Avalanche current	(Note 1)	IAR	-11	A
Channel temperature		Tch	150	℃
Storage temperature ra	ange	T _{stg}	-55 to 150	°C

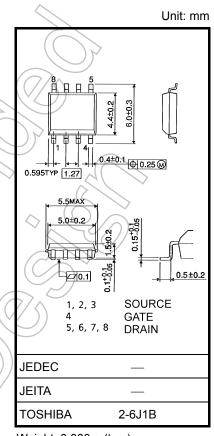
Note 1, Note 2, Note 3 : See the next page.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating

temperature/current/voltage, etc.) are within the absolute maximum ratings.

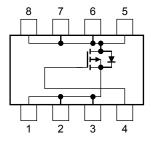
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

This transistor is an electrostatic-sensitive device. Handle with care.



Weight: 0.080 g (typ.)

Circuit Configuration



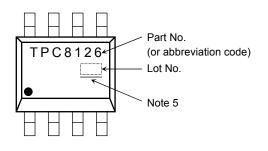
Start of commercial production 2009-10

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Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient (t = 10 s) (Note 2a)	R _{th (ch-a)}	65.8	°C/W
Thermal resistance, channel to ambient (t = 10 s) (Note 2b)	R _{th (ch-a)}	125	°C/W

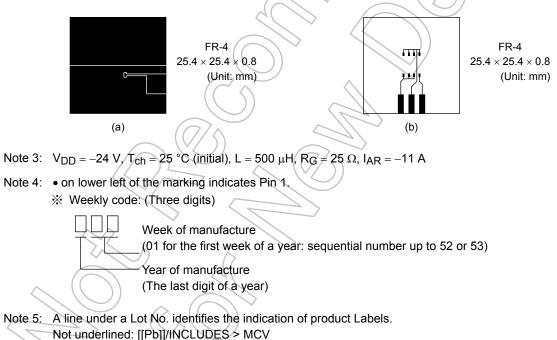
Marking (Note 4)



Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: (a)Device mounted on a glass-epoxy board (a)

(b)Device mounted on a glass-epoxy board (b)



Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Electrical Characteristics (Ta = 25°C)

Cha	racteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage curr	ent	I _{GSS}	$V_{GS}=\pm 20~V,~V_{DS}=0~V$			±100	nA
Drain cut-OFF cur	rent	I _{DSS}	$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			-10	μA
Drain-source breakdown voltage		V (BR) DSS	$I_D = -10 \text{ mA}, V_{GS} = 0 \text{ V}$	-30			V
		V (BR) DSX	$I_D = -10 \text{ mA}, V_{GS} = 10 \text{ V}$ (Note 6)	-21	_	_	V
Gate threshold vol	tage	V _{th}	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -0.5 \text{ mA}$	-0.8)/	-2.0	V
Drain-source ON-resistance		Pro (ou)	$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -5.5 \text{ A}$	77	10.5	14	mΩ
		R _{DS (ON)}	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -5.5 \text{ A}$	Θ	7.5	10	
Input capacitance		C _{iss}			2400	_	
Reverse transfer capacitance		C _{rss}	$V_{DS} = -10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	_	400	_	pF
Output capacitance		C _{oss}			460	_	
Switching time	Rise time	tr	$V_{GS} = -5.5A$ $V_{GS} = -10 V$ G G V	-	8	>	• ns
	Turn-ON time	t _{on}		_((16) —	
	Fall time	t _f		20	65		
	Turn-OFF time	t _{off}	$V_{DD} \approx -15 V$ Duty $\leq 1\%$, $t_W = 10 \ \mu s$	Z	200		
Total gate charge (gate-source plus gate-drain)		Qg	$V_{DD} \approx -24 \text{ V}, \text{ V}_{GS} = -10 \text{ V},$	/	56		
Gate-source charge 1		Q _{gs1}	$I_D = -11 \text{ A}$		5.6	_	nC
Gate-drain ("miller") charge		Q _{gd}			15		

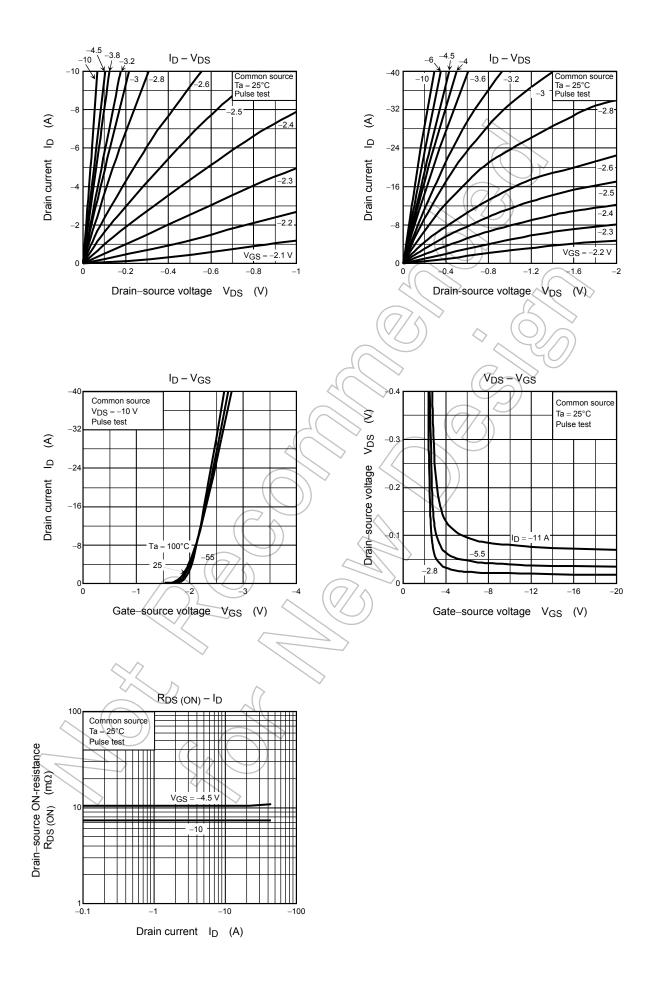
Source-Drain Ratings and Characteristics (Ta = 25° C)

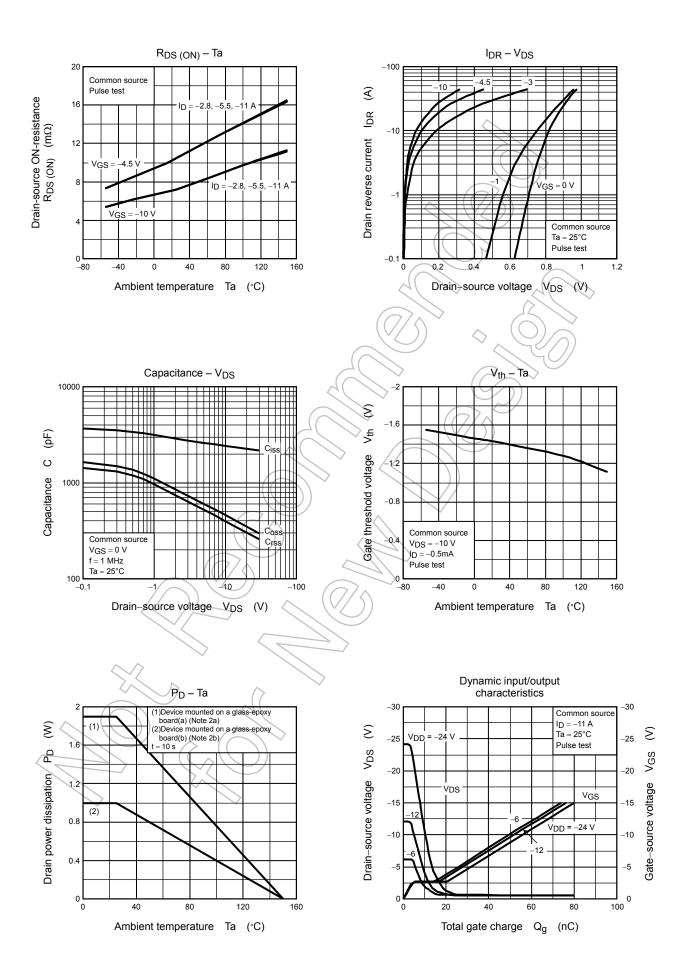
Charao	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Drain reverse current	Pulse (Note 1)	IDRP	(()) -	_	_	-44	А
Forward voltage (dio	ode)	VDSF	I _{DR} = -11 A, V _{GS} = 0 V	—		1.2	V

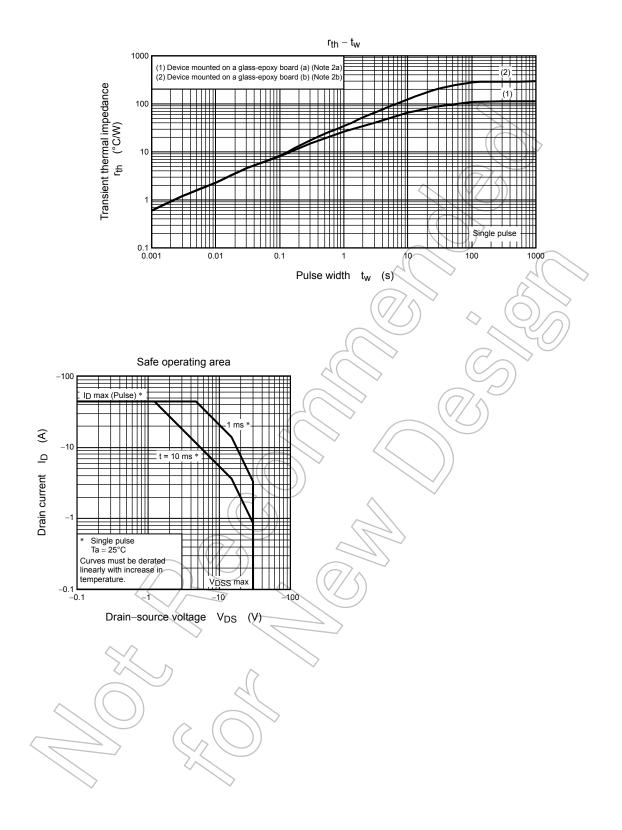
Note 6: VDSX mode (the application of a plus voltage between gate and source) may cause decrease in maximum rating of drain-source voltage.



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